APPROVAL SHEET

MULTILAYER CERAMIC CAPACITORS
Capacitor Arrays Series (10V to 100V)
4 x 0402, 4 x 0603 Sizes
NP0, X7R & Y5V Dielectrics
Halogen Free & RoHS Compliance

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^{*}Contents in this sheet are subject to change without prior notice.

1. INTRODUCTION

Thunder middle and high voltage series MLCC is designed by a special internal electrode pattern, which can reduce voltage concentrations by distributing voltage gradients throughout the entire capacitor. This special design also affords increased capacitance values in a given case size and voltage rating.

Thunder capacitor arrays are developed to offer designers the opportunity to lower placement costs increase assembly line output through lower component count per board.

2. **FEATURES**

- High density mounting due to mounting space saving.
- b. Mounting cost saving.
- c. Increased throughput.

3. APPLICATIONS

- For use as a bypass for digital and analog signal line noise
- b. Computer motherboards and peripherals.
- c. The other common electronic circuits.

4. HOW TO ORDER

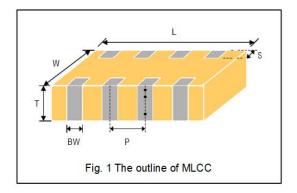
Y	<u>4C</u>	<u>3</u>	В	<u>103</u>	K	<u>500</u>	<u>C</u>	I
<u>Series</u>	Cap. Nr.	Termination pitch	Dielectric	Capacitance	<u>Tolerance</u>	Rated voltage	<u>Termination</u>	<u>Packaging</u>
Y =Capacitor array	4C =4xCap	3=0.03" pitch* 2=0.02" pitch*	N =NP0 (C0G) B =X7R F =Y5V	Two significant digits followed by no. of zeros. And R is in	J=±5% K=±10% M=±20% Z=-20/+80%	Two significant digits followed by no. of zeros. And R is in	C=Cu/Ni/Sn	T=7" reeled
	′4C3: 4x0603	` '		place of decimal point.		place of decimal point.		
Y4C2: 4x0402 (0508)				eg.: 103=10x10 ³ =10,000pF =10nF		eg.: 100=10 VDC 160=16 VDC 250=25 VDC 500=50 VDC 101=100 VDC		

^{*}Size/ Inch (mm) : 4x0402=0508 (1220), 4x0603=0612 (1632)

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5. EXTERNAL DIMENSIONS



Size Inch (mm)	L (mm)	W (mm)	T (mm)/Sym	bol	S (mm)	BW (mm)	P (mm)
4x0402 0508 (1220)	2.00±0.15	1.25±0.15	0.85±0.10	Т	0.20±0.10	0.25±0.10	0.50±0.10
4x0603 0612 (1632)	3.20±0.15	1.60±0.15	0.80±0.10	В	0.30±0.20	0.40±0.15	0.80±0.15

Reflow soldering process only.

6. GENERAL ELECTRICAL DATA

Dielectric	NF	- 0	X7	X7R		
Size	4x0402	4x0603	4x0402	4x0603	4x0603	
Inch (mm)	0508 (1220)	0612 (1632)	0508 (1220)	0612 (1632)	0612 (1632)	
Capacitance*	10pF to 270pF	10pF to 470pF	1000pF to 100nF	150pF to 100nF	10nF to 100nF	
Capacitance tolerance**	J (±5%), K (±10%)		K (±10%),	Z (-20/+80%)		
Rated voltage (WVDC)	25, 50V, 100V		10V, 16V, 25V, 50V	16V, 25V, 50V	16V, 50V	
Q/Tan δ*	Cap<30pF: Q≥400+20C Cap≥30pF: Q≥1000		Ur=50V, ≤2.5% Ur=25V&16V, ≤3.5% Ur=10V, ≤5.0%		Ur=50V, ≤5% Ur=16V, ≤7%	
Insulation resistance at Ur	≥10	GΩ	≥10GΩ (chever is less		
Operating temperature		-55 to	+125℃	-25 to +85℃		
Capacitance characteristic	±30ppm		±15	+30/-80%		
Termination	Ni/Sn (lead-free termination)					

^{*} Measured at 30~70% related humidity.

NP0: Apply 1.0±0.2Vrms, 1.0MHz±10% at the conditions of 25℃ ambient temperature.

X7R: Apply 1.0 \pm 0.2Vrms, 1.0kHz \pm 10%, at the conditions of 25°C ambient temperature.

Y5V: Apply 1.0±0.2Vrms, 1.0kHz±10%, at the conditions of 20℃ ambient temperature.

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^{**} Preconditioning for Class II MLCC: Perform a heat treatment at 150±10℃ for 1 hour, then leave in a mbient condition for 24±2 hours before measurement.

7. CAPACITANCE RANGE

	SIZE Inch (mm)			0	4 x 040 508 (12				-				0603 2 (1632)			
	DIELECTRIC		NPO X7R			NPO X7R				Y	Y5V					
RAT	ED VOLTAGE (VDC)	25	50	100	10	16	25	50	25	50	100	16	25	50	16	50
	10pF (100)	Т	Т	Т					В	В	В					
	15pF (150)	Т	Т	Т					В	В	В					
	22pF (220)	Т	Т	Т					В	В	В					
	33pF (330)	Т	Т	Т					В	В	В					
	47pF (470)	Т	Т	Т					В	В	В					
	68pF (680)	Т	Т	Т					В	В	В					
	100pF (101)	Т	Т	Т					В	В	В					
	120pF (121)	Т	Т	Т					В	В	В					
	150pF (151)	Т	Т	Т					В	В	В		В	В		
	180pF (181)	T	Т	Т					В	В	В		В	В		
	220pF (221)	Т	Т	Т					В	В	В		В	В		
	270pF (271)	Т	Т	Т					В	В	В		В	В		
Capacitance	330pF (331)								В	В	В		В	В		
ig	470pF (471)								В	В	В		В	В		
bac	6,80pF (681)												В	В		
ပ္မ	1,000pF (102)				Т	Т	Т	Т					В	В		
	1,500pF (152)				Т	Т	Т	Т					В	В		
	2,200pF (222)				T	Т	Т	Т					В	В		
	3,300pF (332)				Т	Т	Т	Т					В	В		
	4,700pF (472)				Т	Т	Т	Т					В	В		
	6,800pF (682)				Т	Т	Т	Т					В	В		
	0.010 μ F (103)				Т	Т	Т	Т					В	В		В
	0.015 μ F (153)				Т	Т	Т					В	В	В		В
	0.022μF (223)				Т	Т	Т					В	В	В		В
	0.033 μ F (333)				Т	Т	Т					В				В
	0.047 μ F (473)				Т	Т	Т					В				В
	0.068 μ F (683)				Т	Т	Т					В				В
	0.10 μ F (104)				Т	Т	Т					В			В	В

^{1.} The letter in cell is expressed the symbol of product thickness.

8. PACKAGING DIMENSION AND QUANTITY

SIZE	Thickness/Syn	nbol	Paper tape		
Inch (mm)	(mm)		7" reel	13" reel	
4x0402	0.85±0.10	т	416	-	
0508 (1220)	0.05±0.10	'	4k		
4x0603	0.80±0.10	В	4k	-	
0612 (1632)	0.60±0.10		4K		

Unit: pieces

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9. RELIABILITY TEST CONDITIONS AND REQUIREMENTS

No.	Item	Test Condition			Requirements		
1.	Visual and	 			* No remark	kable defect.	
	Mechanical				* Dimensions to conform to individual specification sheet.		
2.	Capacitance	Class I: (NP0)			* Shall not exceed the limits given in the detailed spec.		
3.	Q/ D.F.	1.0±0.2Vms	, 1MHz±10%		tenness and f	o≥30pF, Q≥1000; Cap<30pF, Q≥400+20C	
	(Dissipation	Class II: (X7F	R, Y5V)		X7R: Ur=50V, ≤2.5%; Ur=25V&16V, ≤3.5%; Ur=10V, ≤5.0%		
	Factor)	1.0±0.2Vms	, 1kHz±10%		Y5V: Ur=	:50V, ≤5%; Ur=16V, ≤7%	
		*Before initia	I measurement (Class II only): To	apply de-aging			
		at 150℃ for 1	1hr then set for 24±2 hrs at room t	emp.			
4.	Dielectric	* To apply 25	0% rated voltage.		* No evider	nce of damage or flash over during test.	
	Strength	* Duration: 1	to 5 sec.				
		* Charge and	d discharge current less than 50m/	A.			
5.	Insulation	To apply rate	ed voltage for max. 120 sec.		≥10GΩ or F	RxC≥500Ω-F whichever is smaller.	
	Resistance	*Before initia	I measurement (Class II only): To	apply de-aging			
		at 150℃ for 1	1hr then set for 24±2 hrs at room t	emp.			
6.	Temperature	With no elect	rical load.				
	Coefficient	T.C.	Operating Temp		T.C.	Capacitance Change	
		NP0	-55~125℃ at 25℃		NP0	Within ±30ppm/℃	
		X7R	-55~125℃ at 25℃		X7R	Within ±15%	
		Y5V	-25~85℃ at 20℃]	Y5V	Within +30%/-80%	
			I measurement (Class II only): To a 1hr then set for 24±2 hrs at room t	,			
7.	Adhesive	* Pressurizin	a force :				
	Strength of		and 10N (>0603)		* No remarkable damage or removal of the terminations.		
	Termination	* Test time: 1	,				
8.	Vibration	* Vibration fre	equency: 10~55 Hz/min.		 		
	Resistance		tude: 1.5mm		* No remar	kable damage.	
			hrs. (Two hrs each in three mutua	ally	* Cap change and Q/D.F.: To meet initial spec.		
		perpendicula	ardirections.)	•			
		*Before initia	I measurement (Class II only): To	apply de-aging			
		at 150℃ for 1	1hr then set for 24±2 hrs at room t	emp.			
		*Cap./DF(Q)	Measurement to be made after de	e-aging at 150℃			
		for 1hr then s	set for 24±2 hrs at room temp.				
9.	Solderability	* Solder temp	perature: 235±5℃		95% min. c	overage of all metalized area.	
	_	* Dipping tim	e: 2±0.5 sec.				
10.	Bending Test	* The middle	part of substrate shall be pressuri	ized by means	* No remarkable damage.		
		of the pressu	rizing rod at a rate of about 1 mm	per second until	Cap change :		
		the deflection	n becomes 1 mm and then the pre	ssure shall be	NP0: within ±5.0% or ±0.5pF whichever is larger.		
		maintained fo	or 5±1 sec.		X7R: within ±12.5%		
		*Before initia	I measurement (Class II only): To	apply de-aging	Y5V: within ±30%		
		at 150℃ for 1	1hr then set for 24±2 hrs at room t	emp.	(This capac	citance change means the change of capacit	ance under
		*Measurement to be made after keeping at room temp. for			specified flexure of substrate from the capacitance measured before		
		24±2 hrs.		the test.)			
		* Solder temperature: 260±5℃		* No remarkable damage.			
11.	Resistance to						
	Soldering Heat	* Dipping time: 10±1 sec			* Cap change:		
		* Preheating:	: 120 to 150℃ for 1 minute before	imme rse the	NP0: within ±2.5% or ±0.25pF whichever is larger.		
		capacitor in a	a eutectic solder.		X7R: with	in ±7.5%	
		*Before initia	I measurement (Class II only): To	apply de-aging	Y5V: with	in ±20%	
		at 150℃ for 1	1hr then set for 24±2 hrs at room t	emp.	* Q/D.F., I.F	R. and dielectric strength: To meet initial requ	irements.
		*Cap. / DF(Q) / I.R. Measurement to be made	after de-aging at	* 25% max.	leaching on each edge.	
		150℃ for 1hr	then set for 24±2 hrs at room tem	ıp.			

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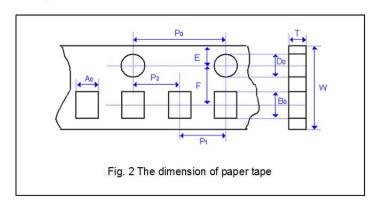


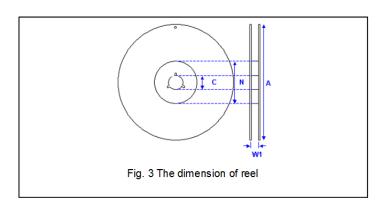
No.	Item		Test Condition		Requirements		
12.	Temperature Cycle	* Conduc	t the five cycles according to the t	emperatures and	* No remarkable damage. * Cap change :		
		Step	Temp. (℃)	Time (min.)	cup change .		
		1 1	Min. operating temp. +0/-3	30±3	NP0: within ±2.5% or ±0.25pF whichever is larger.		
		2	Room temp.	2~3	X7R: within ±7.5%		
		3	Max. operating temp. +3/-0	30±3	Y5V: within ±20%		
		4	Room temp.	2~3	* Q/D.F., I.R. and dielectric strength: To meet initial requirements.		
			Security of the second of the second	25 W 20 E			
			nitial measurement (Class II only):				
			for 1hr then set for 24±2 hrs at roo	APPLIED ACCOUNTS CONT.			
		35	OF(Q) / I.R. Measurement to be m	W= X=			
- į		at 150℃	for 1hr then set for 24±2 hrs at roo	om temp.			
13.	Humidity	* Test ten	np.: 40±2℃				
	(Damp Heat)	* Humidit	y: 90~95% RH		* No remarkable damage.		
	Steady State	* Test tim	e: 500+24/-0hrs.		* Cap change: NP0: within ±5.0% or ±0.5pF whichever is larger.		
	*	*Before in	nitial measurement (Class II only):	To apply de-aging	X7R: within ±12.5%		
		at 150℃ 1	for 1hr then set for 24±2 hrs at roo	om temp.	Y5V: within ±30%		
		* Cap. / D	DF(Q) / I.R. Measurement to be m	ade after de-aging	* Q/D.F. value:		
		at 150℃ 1	for 1hr then set for 24±2 hrs at roo	om temp.			
					NP0: Cap≥30pF, Q≥350; 10pF≤Cap<30pF, Q≥275+2.5C		
					Cap<10pF; Q≥200+10C		
					X7R: Ur=50V, ≤3%; Ur=25V&16V, ≤5%; Ur=10V, ≤7.5%		
					Y5V: Ur=50V, ≤7.5%; Ur=16V, ≤10%		
		-			* I.R.: ≥1GΩ or RxC≥50Ω-F whichever is smaller.		
14.	Humidity	* Test ten	np.: 40±2℃		* No remarkable damage.		
	(Damp Heat)		•				
	Load		:y: 90~95%RH		* Cap change: NP0: within ±7.5% or ±0.75pF whichever is larger.		
		" lest tim	e: 500+24/-0 hrs.		X7R: within ±12.5%		
		* To apply	y voltage: rated voltage.		Y5V: within ±30%		
		*Before ir	nitial measurement (Class II only):	To apply de-aging	* Q/D.F. value:		
		at 150℃ 1	for 1hr then set for 24±2 hrs at roo	om temp.	NP0: Cap≥30pF, Q≥200; Cap<30pF, Q≥100+10/3C X7R:		
		* Cap. / E	DF(Q) / I.R. Measurement to be m	ade after de-aging	Ur=50V, ≤3%; Ur=25V&16V, ≤5%; Ur=10V, ≤7.5% Y5V:		
			for 1hr then set for 24±2 hrs	at room temp.	Ur=50V, ≤7.5%; Ur=16V, ≤10%		
					* I.R.: ≥500MΩ or RxC≥25Ω-F whichever is smaller.		
15.	High				* No remarkable damage.		
	Temperature	* Test ten	•		* Cap change: NP0: within ±3.0% or ±0.3pF whichever is larger.		
	Load	NP0, X7F	R: 125±3℃		X7R: within ±12.5%		
	(Endurance)	Y5V: 85±	3℃		Y5V: within ±30%		
		* To apply	y voltage: 200% of rated voltage.		* Q/D.F. value:		
		* Test tim	e: 1000+24/-0 hrs.				
		*Before ir	nitial measurement (Class II only):	To apply de-aging	NP0: Cap≥30pF, Q≥350		
			for 1hr then set for 24±2 hrs at roo	,	10pF≤Cap<30pF, Q≥275+2.5C		
			DF(Q) / I.R. Measurement to be m	•	Cap<10pF, Q≥200+10C		
					X7R: Ur=50V, ≤3%; Ur=25V&16V, ≤5%; Ur=10V, ≤7.5%		
		at 150°C	for 1hr then set for 24±2 hrs at roo	om temp.	Y5V: Ur=50V, ≤7.5%; Ur=16V, ≤10%		

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APPENDIXES

■ Tape & reel dimensions





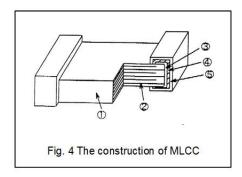
SIZE Inch (mm)	4x0402 0508 (1220)	4x0603 0612 (1632)
Thickness	T	В
\mathbf{A}_0	1.50 +/-0.20	1.90 +/-0.50
B ₀	2.30 +/-0.20	3.50 +/-0.50
Т	≦1.20	≦1.20
K ₀		-
W	8.00 +/-0.10	8.00 +/-0.10
P ₀	4.00 +/-0.10	4.00 +/-0.10
10xP ₀	40.00 +/-0.20	40.00 +/-0.20
P ₁	4.00 +/-0.10	4.00 +/-0.10
P_2	2.00 +/-0.05	2.00 +/-0.05
D_0	1.55 +/-0.05	1.55 +/-0.05
D ₁	-	-
E	1.75 +/-0.05	1.75 +/-0.05
F	3.50 +/-0.05	3.50 +/-0.05

Reel size	7"
С	13.0+0.5/-0.2
W ₁	8.4+1.5/-0
Α	178.0±1.0
N	60.0+1.0/-0

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Constructions

No.	Nai	me	NP0, X7R, Y5V		
1	Ceramic	material	BaTiO₃ based		
2	Inner el	ectrode	Ni		
3	3	Inner layer	Cu		
4	Termination	Middle layer	Ni		
5		Outer layer	Sn (Matt)		



Storage and handling conditions

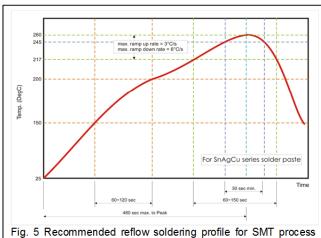
- (1) To store products at 5 to 40°C ambient temperature and 20 to 70%. related humidity conditions.
- (2) The product is recommended to be used within one year after shipment. Check solderability in case of shelf life extension is needed.

Cautions:

- a. The corrosive gas reacts on the terminal electrodes of capacitors, and results in the poor solderability. Do not store the capacitors in the ambience of corrosive gas (e.g., hydrogen sulfide, sulfur dioxide, chlorine, ammonia gas etc.)
- b. In corrosive atmosphere, solderability might be degraded, and silver migration might occur to cause low reliability.
- c. Due to the dewing by rapid humidity change, or the photochemical change of the terminal electrode by direct sunlight, the solderability and electrical performance may deteriorate. Do not store capacitors under direct sunlight or dewing condition. To store products on the shelf and avoid exposure to moisture.

Recommended soldering conditions

The lead-free termination MLCCs are not only to be used on SMT against lead-free solder paste, but also suitable against lead-containing solder paste. If the optimized solder joint is requested, increasing soldering time, temperature and concentration of N₂ within oven are recommended.



with SnAgCu series solder paste.

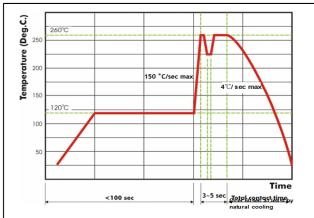


Fig. 6 Recommended wave soldering profile for SMT process with SnAgCu series solder.

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